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### What is "[Embedded - Microcontrollers](#)"?

"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Active
Core Processor	S08
Core Size	8-Bit
Speed	20MHz
Connectivity	I <sup>2</sup> C, LINbus, SPI, UART/USART
Peripherals	LVD, POR, PWM, WDT
Number of I/O	37
Program Memory Size	8KB (8K x 8)
Program Memory Type	FLASH
EEPROM Size	256 x 8
RAM Size	2K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 12x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 105°C (TA)
Mounting Type	Surface Mount
Package / Case	44-LQFP
Supplier Device Package	44-LQFP (10x10)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/nxp-semiconductors/mc9s08pa8avldr">https://www.e-xfl.com/product-detail/nxp-semiconductors/mc9s08pa8avldr</a>

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Field	Description	Values
B	Operating temperature range (°C)	<ul style="list-style-type: none"> <li>• V = –40 to 105</li> </ul>
CC	Package designator	<ul style="list-style-type: none"> <li>• LD = 44-LQFP</li> <li>• LC = 32-LQFP</li> <li>• TJ = 20-TSSOP</li> <li>• WJ = 20-SOIC</li> <li>• TG = 16-TSSOP</li> </ul>

## 2.4 Example

This is an example part number:

MC9S08PA16VLD

## 3 Parameter Classification

The electrical parameters shown in this supplement are guaranteed by various methods. To give the customer a better understanding, the following classification is used and the parameters are tagged accordingly in the tables where appropriate:

**Table 1. Parameter Classifications**

P	Those parameters are guaranteed during production testing on each individual device.
C	Those parameters are achieved by the design characterization by measuring a statistically relevant sample size across process variations.
T	Those parameters are achieved by design characterization on a small sample size from typical devices under typical conditions unless otherwise noted. All values shown in the typical column are within this category.
D	Those parameters are derived mainly from simulations.

### NOTE

The classification is shown in the column labeled “C” in the parameter tables where appropriate.

## 4 Ratings

### 4.1 Thermal handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
T <sub>STG</sub>	Storage temperature	-55	150	°C	1
T <sub>SDR</sub>	Solder temperature, lead-free	—	260	°C	2

1. Determined according to JEDEC Standard JESD22-A103, *High Temperature Storage Life*.
2. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

### 4.2 Moisture handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
MSL	Moisture sensitivity level	—	3	—	1

1. Determined according to IPC/JEDEC Standard J-STD-020, *Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices*.

### 4.3 ESD handling ratings

Symbol	Description	Min.	Max.	Unit	Notes
V <sub>HBM</sub>	Electrostatic discharge voltage, human body model	-6000	+6000	V	1
V <sub>CDM</sub>	Electrostatic discharge voltage, charged-device model	-500	+500	V	2
I <sub>LAT</sub>	Latch-up current at ambient temperature of 105°C	-100	+100	mA	

1. Determined according to JEDEC Standard JESD22-A114, *Electrostatic Discharge (ESD) Sensitivity Testing Human Body Model (HBM)*.
2. Determined according to JEDEC Standard JESD22-C101, *Field-Induced Charged-Device Model Test Method for Electrostatic-Discharge-Withstand Thresholds of Microelectronic Components*.

### 4.4 Voltage and current operating ratings

Absolute maximum ratings are stress ratings only, and functional operation at the maxima is not guaranteed. Stress beyond the limits specified in below table may affect device reliability or cause permanent damage to the device. For functional operating conditions, refer to the remaining tables in this document.

This device contains circuitry protecting against damage due to high static voltage or electrical fields; however, it is advised that normal precautions be taken to avoid application of any voltages higher than maximum-rated voltages to this high-impedance circuit. Reliability of operation is enhanced if unused inputs are tied to an appropriate logic voltage level (for instance, either  $V_{SS}$  or  $V_{DD}$ ) or the programmable pullup resistor associated with the pin is enabled.

Symbol	Description	Min.	Max.	Unit
$V_{DD}$	Supply voltage	-0.3	6.0	V
$I_{DD}$	Maximum current into $V_{DD}$	—	120	mA
$V_{DIO}$	Digital input voltage (except RESET, EXTAL, XTAL, or true open drain pin PTA2 and PTA3)	-0.3	$V_{DD} + 0.3$	V
	Digital input voltage (true open drain pin PTA2 and PTA3)	-0.3	6	V
$V_{AIO}$	Analog <sup>1</sup> , RESET, EXTAL, and XTAL input voltage	-0.3	$V_{DD} + 0.3$	V
$I_D$	Instantaneous maximum current single pin limit (applies to all port pins)	-25	25	mA
$V_{DDA}$	Analog supply voltage	$V_{DD} - 0.3$	$V_{DD} + 0.3$	V

1. All digital I/O pins, except open-drain pin PTA2 and PTA3, are internally clamped to  $V_{SS}$  and  $V_{DD}$ . PTA2 and PTA3 is only clamped to  $V_{SS}$ .

## 5 General

### 5.1 Nonswitching electrical specifications

#### 5.1.1 DC characteristics

This section includes information about power supply requirements and I/O pin characteristics.

**Table 2. DC characteristics**

Symbol	C	Descriptions			Min	Typical <sup>1</sup>	Max	Unit
—	—	Operating voltage		—	2.7	—	5.5	V
$V_{OH}$	C	Output high voltage	All I/O pins, standard-drive strength	5 V, $I_{load} = -5$ mA	$V_{DD} - 0.8$	—	—	V
	C			3 V, $I_{load} = -2.5$ mA	$V_{DD} - 0.8$	—	—	V
	C		High current drive pins, high-drive strength <sup>2</sup>	5 V, $I_{load} = -20$ mA	$V_{DD} - 0.8$	—	—	V
	C			3 V, $I_{load} = -10$ mA	$V_{DD} - 0.8$	—	—	V

Table continues on the next page...

6. Power supply must maintain regulation within operating  $V_{DD}$  range during instantaneous and operating maximum current conditions. If the positive injection current ( $V_{IN} > V_{DD}$ ) is higher than  $I_{DD}$ , the injection current may flow out of  $V_{DD}$  and could result in external power supply going out of regulation. Ensure that external  $V_{DD}$  load will shunt current higher than maximum injection current when the MCU is not consuming power, such as no system clock is present, or clock rate is very low (which would reduce overall power consumption).

**Table 3. LVD and POR Specification**

Symbol	C	Description		Min	Typ	Max	Unit
V <sub>POR</sub>	D	POR re-arm voltage <sup>1, 2</sup>		1.5	1.75	2.0	V
V <sub>LVDH</sub>	C	Falling low-voltage detect threshold - high range (LVDV = 1) <sup>3</sup>		4.2	4.3	4.4	V
V <sub>LVW1H</sub>	C	Falling low-voltage warning threshold - high range	Level 1 falling (LVWV = 00)	4.3	4.4	4.5	V
V <sub>LVW2H</sub>	C		Level 2 falling (LVWV = 01)	4.5	4.5	4.6	V
V <sub>LVW3H</sub>	C		Level 3 falling (LVWV = 10)	4.6	4.6	4.7	V
V <sub>LVW4H</sub>	C		Level 4 falling (LVWV = 11)	4.7	4.7	4.8	V
V <sub>HYSH</sub>	C	High range low-voltage detect/warning hysteresis		—	100	—	mV
V <sub>LVDL</sub>	C	Falling low-voltage detect threshold - low range (LVDV = 0)		2.56	2.61	2.66	V
V <sub>LVDW1L</sub>	C	Falling low-voltage warning threshold - low range	Level 1 falling (LVWV = 00)	2.62	2.7	2.78	V
V <sub>LVDW2L</sub>	C		Level 2 falling (LVWV = 01)	2.72	2.8	2.88	V
V <sub>LVDW3L</sub>	C		Level 3 falling (LVWV = 10)	2.82	2.9	2.98	V
V <sub>LVDW4L</sub>	C		Level 4 falling (LVWV = 11)	2.92	3.0	3.08	V
V <sub>HYSDL</sub>	C	Low range low-voltage detect hysteresis		—	40	—	mV
V <sub>HYSWL</sub>	C	Low range low-voltage warning hysteresis		—	80	—	mV
V <sub>BG</sub>	P	Buffered bandgap output <sup>4</sup>		1.14	1.16	1.18	V

1. Maximum is highest voltage that POR is guaranteed.
2. POR ramp time must be longer than 20us/V to get a stable startup.
3. Rising thresholds are falling threshold + hysteresis.
4. Voltage factory trimmed at  $V_{DD} = 5.0$  V, Temp = 25 °C

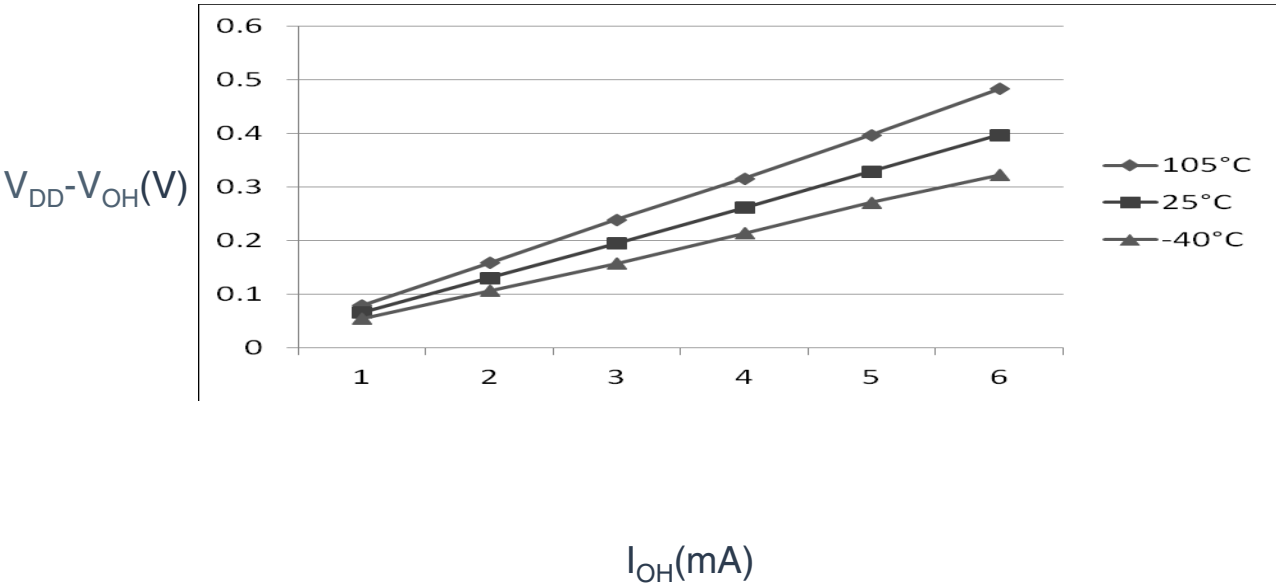


Figure 1. Typical I<sub>OH</sub> Vs. V<sub>DD</sub>-V<sub>OH</sub> (standard drive strength) (V<sub>DD</sub> = 5 V)

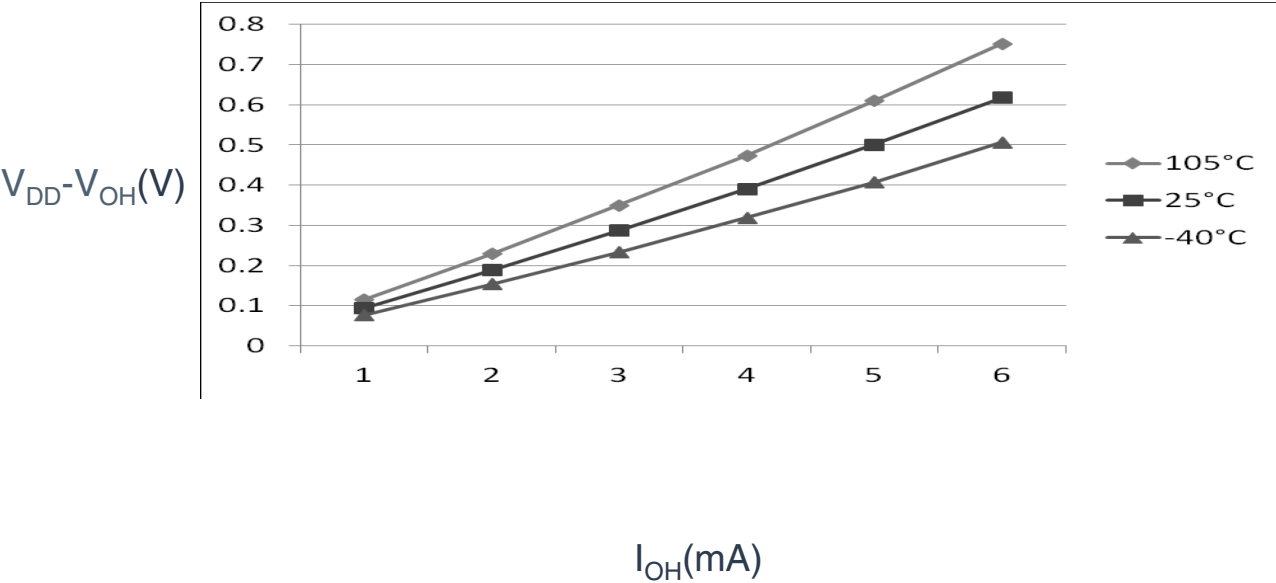


Figure 2. Typical I<sub>OH</sub> Vs. V<sub>DD</sub>-V<sub>OH</sub> (standard drive strength) (V<sub>DD</sub> = 3 V)

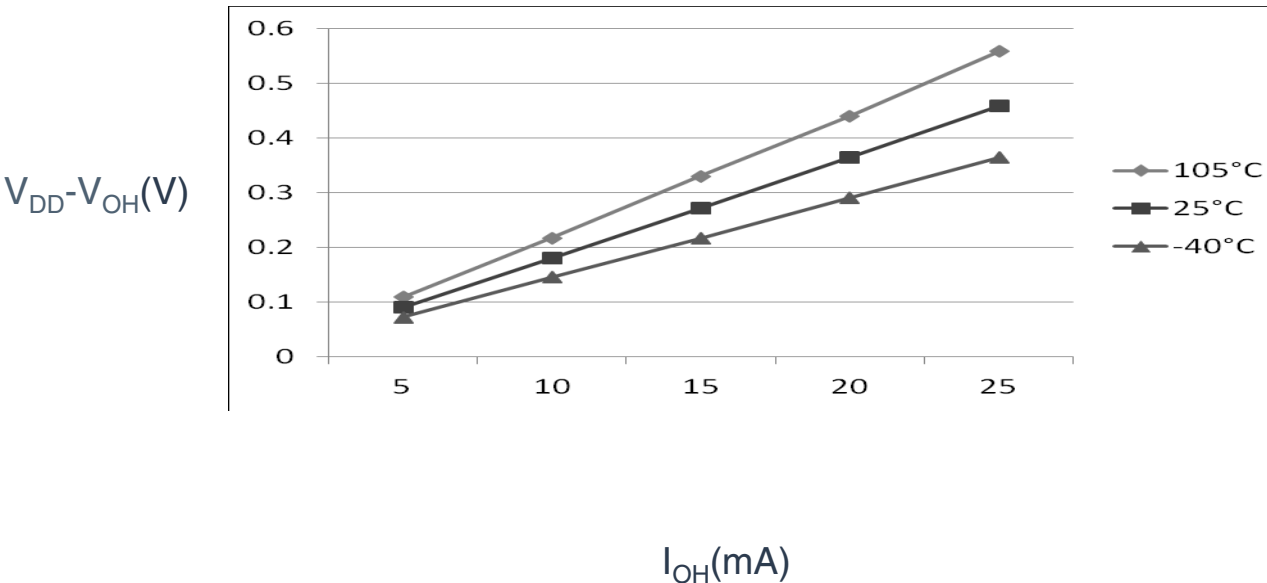


Figure 3. Typical I<sub>OH</sub> Vs. V<sub>DD</sub>-V<sub>OH</sub> (high drive strength) (V<sub>DD</sub> = 5 V)

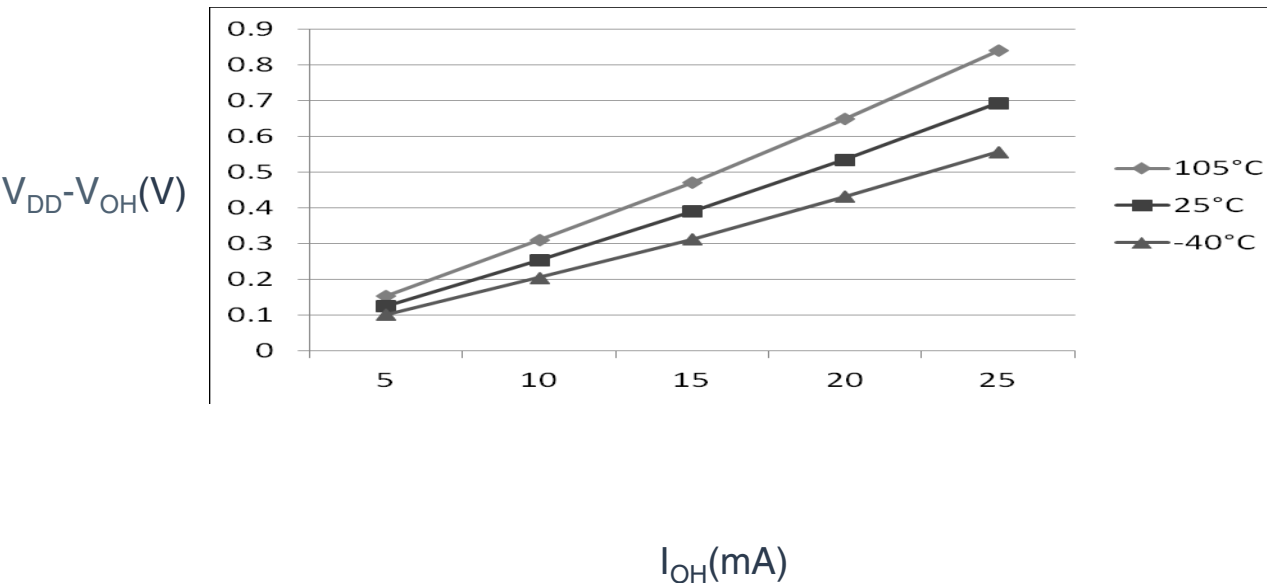


Figure 4. Typical I<sub>OH</sub> Vs. V<sub>DD</sub>-V<sub>OH</sub> (high drive strength) (V<sub>DD</sub> = 3 V)



## 5.1.2 Supply current characteristics

This section includes information about power supply current in various operating modes.

**Table 4. Supply current characteristics**

Num	C	Parameter	Symbol	Bus Freq	V <sub>DD</sub> (V)	Typical <sup>1</sup>	Max	Unit	Temp
1	C	Run supply current FEI mode, all modules on; run from flash	RI <sub>DD</sub>	20 MHz	5	7.60	—	mA	-40 to 105 °C
	C			10 MHz		4.65	—		
	C			1 MHz		1.90	—		
	C			20 MHz	3	7.05	—		
	C			10 MHz		4.40	—		
	C			1 MHz		1.85	—		
2	C	Run supply current FEI mode, all modules off & gated; run from flash	RI <sub>DD</sub>	20 MHz	5	5.88	—	mA	-40 to 105 °C
	C			10 MHz		3.70	—		
	C			1 MHz		1.85	—		
	C			20 MHz	3	5.35	—		
	C			10 MHz		3.42	—		
	C			1 MHz		1.80	—		
3	P	Run supply current FBE mode, all modules on; run from RAM	RI <sub>DD</sub>	20 MHz	5	10.9	14.0	mA	-40 to 105 °C
	C			10 MHz		6.10	—		
	C			1 MHz		1.69	—		
	P			20 MHz	3	8.18	—		
	C			10 MHz		5.14	—		
	C			1 MHz		1.44	—		
4	P	Run supply current FBE mode, all modules off & gated; run from RAM	RI <sub>DD</sub>	20 MHz	5	8.50	13.0	mA	-40 to 105 °C
	C			10 MHz		5.07	—		
	C			1 MHz		1.59	—		
	P			20 MHz	3	6.11	—		
	C			10 MHz		4.10	—		
	C			1 MHz		1.34	—		
5	P	Wait mode current FEI mode, all modules on	WI <sub>DD</sub>	20 MHz	5	5.95	—	mA	-40 to 105 °C
	C			10 MHz		3.50	—		
	C			1 MHz		1.24	—		
	C			20 MHz	3	5.45	—		
	C			10 MHz		3.25	—		
	C			1 MHz		1.20	—		
6	C	Stop3 mode supply current no clocks active (except 1kHz LPO clock) <sup>2,3</sup>	S3I <sub>DD</sub>	—	5	4.6	—	μA	-40 to 105 °C
	C			—	3	4.5	—		-40 to 105 °C
7	C	ADC adder to stop3	—	—	5	40	—	μA	-40 to 105 °C

Table continues on the next page...

**Table 4. Supply current characteristics (continued)**

Num	C	Parameter	Symbol	Bus Freq	V <sub>DD</sub> (V)	Typical <sup>1</sup>	Max	Unit	Temp
	C	ADLPC = 1 ADLSMP = 1 ADCO = 1 MODE = 10B ADICLK = 11B			3	39	—		
8	C	LVD adder to stop3 <sup>4</sup>	—	—	5	128	—	μA	-40 to 105 °C
	C				3	124	—		

1. Data in Typical column was characterized at 5.0 V, 25 °C or is typical recommended value.
2. RTC adder cause <1 μA I<sub>DD</sub> increase typically, RTC clock source is 1kHz LPO clock.
3. ACMP adder cause <10 μA I<sub>DD</sub> increase typically.
4. LVD is periodically woken up from stop3 by 5% duty cycle. The period is equal to or less than 2 ms.

### 5.1.3 EMC performance

Electromagnetic compatibility (EMC) performance is highly dependent on the environment in which the MCU resides. Board design and layout, circuit topology choices, location and characteristics of external components as well as MCU software operation all play a significant role in EMC performance. The system designer should consult Freescale applications notes such as [AN2321](#), [AN1050](#), [AN1263](#), [AN2764](#), and [AN1259](#) for advice and guidance specifically targeted at optimizing EMC performance.

#### 5.1.3.1 EMC radiated emissions operating behaviors

**Table 5. EMC radiated emissions operating behaviors for 44-pin LQFP package**

Symbol	Description	Frequency band (MHz)	Typ.	Unit	Notes
V <sub>RE1</sub>	Radiated emissions voltage, band 1	0.15–50	8	dBμV	1, 2
V <sub>RE2</sub>	Radiated emissions voltage, band 2	50–150	8	dBμV	
V <sub>RE3</sub>	Radiated emissions voltage, band 3	150–500	8	dBμV	
V <sub>RE4</sub>	Radiated emissions voltage, band 4	500–1000	5	dBμV	
V <sub>RE_IEC</sub>	IEC level	0.15–1000	N	—	2, 3

1. Determined according to IEC Standard 61967-1, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 1: General Conditions and Definitions* and IEC Standard 61967-2, *Integrated Circuits - Measurement of Electromagnetic Emissions, 150 kHz to 1 GHz Part 2: Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method*. Measurements were made while the microcontroller was running basic application code. The reported emission level is the value of the maximum measured emission, rounded up to the next whole number, from among the measured orientations in each frequency range.
2. V<sub>DD</sub> = 5.0 V, T<sub>A</sub> = 25 °C, f<sub>OSC</sub> = 10 MHz (crystal), f<sub>SYS</sub> = 20 MHz, f<sub>BUS</sub> = 20 MHz
3. Specified according to Annex D of IEC Standard 61967-2, *Measurement of Radiated Emissions—TEM Cell and Wideband TEM Cell Method*

## 5.2 Switching specifications

### 5.2.1 Control timing

Table 6. Control timing

Num	C	Rating		Symbol	Min	Typical <sup>1</sup>	Max	Unit
1	P	Bus frequency ( $t_{cyc} = 1/f_{Bus}$ )		$f_{Bus}$	DC	—	20	MHz
2	C	Internal low power oscillator frequency		$f_{LPO}$	—	1.0	—	KHz
3	D	External reset pulse width <sup>2</sup>		$t_{extrst}$	$1.5 \times t_{cyc}$	—	—	ns
4	D	Reset low drive		$t_{rstdrv}$	$34 \times t_{cyc}$	—	—	ns
5	D	BKGD/MS setup time after issuing background debug force reset to enter user or BDM modes		$t_{MSSU}$	500	—	—	ns
6	D	BKGD/MS hold time after issuing background debug force reset to enter user or BDM modes <sup>3</sup>		$t_{MSH}$	100	—	—	ns
7	D	IRQ pulse width	Asynchronous path <sup>2</sup>	$t_{ILIH}$	100	—	—	ns
	D		Synchronous path <sup>4</sup>	$t_{IHIL}$	$1.5 \times t_{cyc}$	—	—	ns
8	D	Keyboard interrupt pulse width	Asynchronous path <sup>2</sup>	$t_{ILIH}$	100	—	—	ns
	D		Synchronous path	$t_{IHIL}$	$1.5 \times t_{cyc}$	—	—	ns
9	C	Port rise and fall time - standard drive strength (load = 50 pF) <sup>5</sup>	—	$t_{Rise}$	—	10.2	—	ns
	C		—	$t_{Fall}$	—	9.5	—	ns
	C	Port rise and fall time - high drive strength (load = 50 pF) <sup>5</sup>	—	$t_{Rise}$	—	5.4	—	ns
	C		—	$t_{Fall}$	—	4.6	—	ns

- Typical values are based on characterization data at  $V_{DD} = 5.0$  V, 25 °C unless otherwise stated.
- This is the shortest pulse that is guaranteed to be recognized as a reset pin request.
- To enter BDM mode following a POR, BKGD/MS must be held low during the powerup and for a hold time of  $t_{MSH}$  after  $V_{DD}$  rises above  $V_{LVD}$ .
- This is the minimum pulse width that is guaranteed to pass through the pin synchronization circuitry. Shorter pulses may or may not be recognized. In stop mode, the synchronizer is bypassed so shorter pulses can be recognized.
- Timing is shown with respect to 20%  $V_{DD}$  and 80%  $V_{DD}$  levels. Temperature range -40 °C to 105 °C.

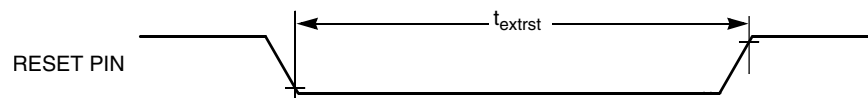


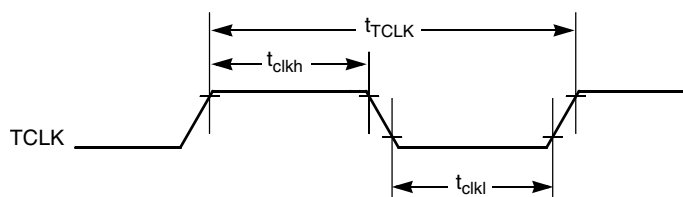
Figure 9. Reset timing

### 5.2.3 FTM module timing

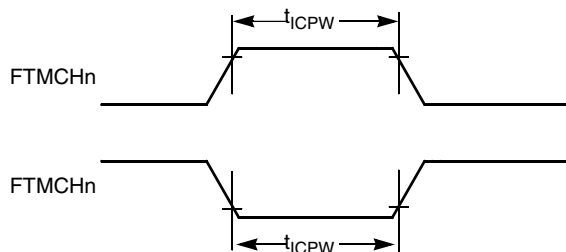
Synchronizer circuits determine the shortest input pulses that can be recognized or the fastest clock that can be used as the optional external source to the timer counter. These synchronizers operate from the current bus rate clock.

**Table 8. FTM input timing**

No.	C	Function	Symbol	Min	Max	Unit
1	D	External clock frequency	$f_{TCLK}$	0	$f_{Bus}/4$	Hz
2	D	External clock period	$t_{TCLK}$	4	—	$t_{cyc}$
3	D	External clock high time	$t_{clkh}$	1.5	—	$t_{cyc}$
4	D	External clock low time	$t_{clkl}$	1.5	—	$t_{cyc}$
5	D	Input capture pulse width	$t_{ICPW}$	1.5	—	$t_{cyc}$



**Figure 13. Timer external clock**



**Figure 14. Timer input capture pulse**

## 6.1 External oscillator (XOSC) and ICS characteristics

**Table 10. XOSC and ICS specifications (temperature range = -40 to 105 °C ambient)**

Num	C	Characteristic		Symbol	Min	Typical <sup>1</sup>	Max	Unit
1	C	Oscillator crystal or resonator	Low range (RANGE = 0)	$f_{lo}$	31.25	32.768	39.0625	kHz
	C		High range (RANGE = 1) FEE or FBE mode <sup>2</sup>	$f_{hi}$	4	—	20	MHz
	C		High range (RANGE = 1), high gain (HGO = 1), FBELP mode	$f_{hi}$	4	—	20	MHz
	C		High range (RANGE = 1), low power (HGO = 0), FBELP mode	$f_{hi}$	4	—	20	MHz
2	D	Load capacitors		C1, C2	See Note <sup>3</sup>			
3	D	Feedback resistor	Low Frequency, Low-Power Mode <sup>4</sup>	$R_F$	—	—	—	MΩ
			Low Frequency, High-Gain Mode		—	10	—	MΩ
			High Frequency, Low-Power Mode		—	1	—	MΩ
			High Frequency, High-Gain Mode		—	1	—	MΩ
4	D	Series resistor - Low Frequency	Low-Power Mode <sup>4</sup>	$R_S$	—	—	—	kΩ
			High-Gain Mode		—	200	—	kΩ
5	D	Series resistor - High Frequency	Low-Power Mode <sup>4</sup>	$R_S$	—	—	—	kΩ
	D	Series resistor - High Frequency, High-Gain Mode	4 MHz		—	0	—	kΩ
	D		8 MHz		—	0	—	kΩ
	D		16 MHz		—	0	—	kΩ
6	C	Crystal start-up time Low range = 32.768 kHz crystal; High range = 20 MHz crystal <sup>5, 6</sup>	Low range, low power	$t_{CSTL}$	—	1000	—	ms
	C		Low range, high power		—	800	—	ms
	C		High range, low power	$t_{CSTH}$	—	3	—	ms
	C		High range, high power		—	1.5	—	ms
7	T	Internal reference start-up time		$t_{IRST}$	—	20	50	μs
8	D	Square wave input clock frequency	FEE or FBE mode <sup>2</sup>	$f_{extal}$	0.03125	—	5	MHz
	D		FBELP mode		0	—	20	MHz
9	P	Average internal reference frequency - trimmed		$f_{int\_t}$	—	31.25	—	kHz
10	P	DCO output frequency range - trimmed		$f_{dco\_t}$	16	—	20	MHz
11	P	Total deviation of DCO output from trimmed frequency <sup>5</sup>	Over full voltage and temperature range	$\Delta f_{dco\_t}$	—	—	±2.0	% $f_{dco}$
	C		Over fixed voltage and temperature range of 0 to 70 °C				±1.0	
12	C	FLL acquisition time <sup>5, 7</sup>		$t_{Acquire}$	—	—	2	ms

Table continues on the next page...

## 6.3 Analog

### 6.3.1 ADC characteristics

**Table 12. 5 V 12-bit ADC operating conditions**

Characteristic	Conditions	Symb	Min	Typ <sup>1</sup>	Max	Unit	Comment
Supply voltage	Absolute	$V_{DDA}$	2.7	—	5.5	V	—
	Delta to $V_{DD}$ ( $V_{DD}-V_{DDAD}$ )	$\Delta V_{DDA}$	-100	0	+100	mV	
Ground voltage	Delta to $V_{SS}$ ( $V_{SS}-V_{SSA}$ ) <sup>2</sup>	$\Delta V_{SSA}$	-100	0	+100	mV	
Input voltage		$V_{ADIN}$	$V_{REFL}$	—	$V_{REFH}$	V	
Input capacitance		$C_{ADIN}$	—	4.5	5.5	pF	
Input resistance		$R_{ADIN}$	—	3	5	k $\Omega$	—
Analog source resistance	12-bit mode	$R_{AS}$	—	—	2	k $\Omega$	External to MCU
	• $f_{ADCK} > 4$ MHz		—	—	5		
	• $f_{ADCK} < 4$ MHz		—	—	5		
	10-bit mode		—	—	5		
	• $f_{ADCK} > 4$ MHz		—	—	10		
	• $f_{ADCK} < 4$ MHz		—	—	10		
ADC conversion clock frequency	8-bit mode (all valid $f_{ADCK}$ )		—	—	10		
	High speed (ADLPC=0)	$f_{ADCK}$	0.4	—	8.0	MHz	—
	Low power (ADLPC=1)		0.4	—	4.0		

1. Typical values assume  $V_{DDA} = 5.0$  V, Temp = 25°C,  $f_{ADCK}=1.0$  MHz unless otherwise stated. Typical values are for reference only and are not tested in production.
2. DC potential difference.

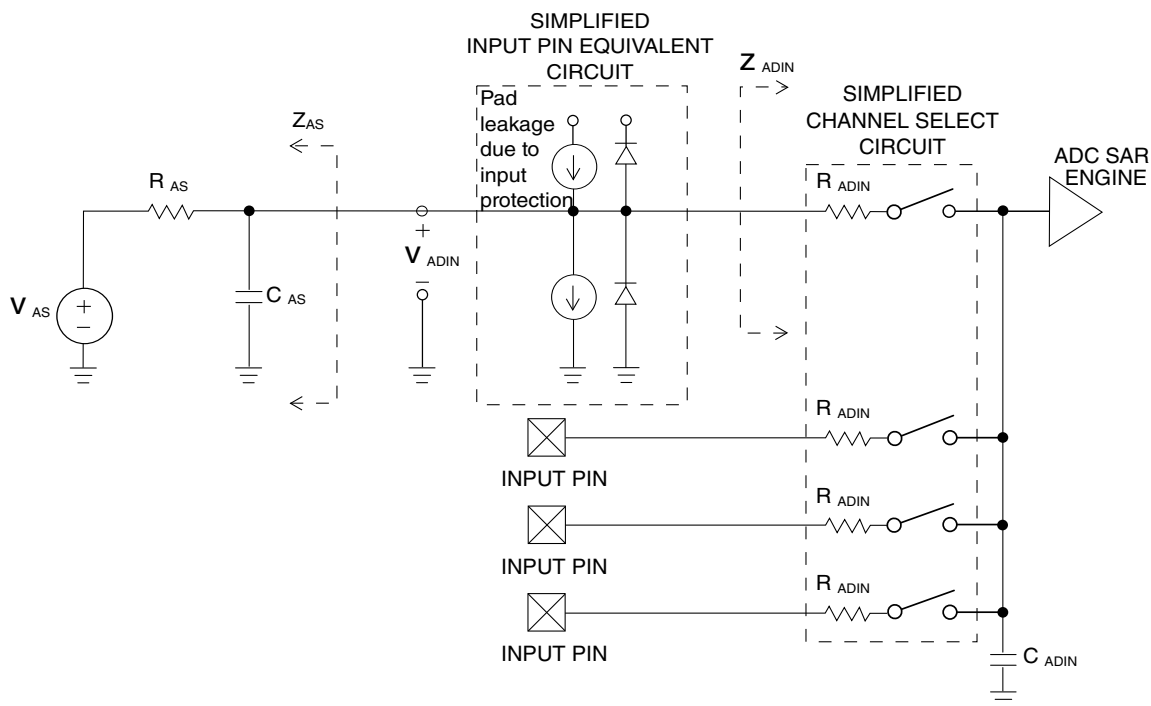


Figure 16. ADC input impedance equivalency diagram

Table 13. 12-bit ADC Characteristics ( $V_{REFH} = V_{DDA}$ ,  $V_{REFL} = V_{SSA}$ )

Characteristic	Conditions	C	Symb	Min	Typ <sup>1</sup>	Max	Unit
Supply current ADLPC = 1 ADLSMP = 1 ADCO = 1		T	$I_{DDA}$	—	133	—	$\mu A$
Supply current ADLPC = 1 ADLSMP = 0 ADCO = 1		T	$I_{DDA}$	—	218	—	$\mu A$
Supply current ADLPC = 0 ADLSMP = 1 ADCO = 1		T	$I_{DDA}$	—	327	—	$\mu A$
Supply current ADLPC = 0 ADLSMP = 0 ADCO = 1		T	$I_{DDAD}$	—	582	990	$\mu A$
Supply current	Stop, reset, module off	T	$I_{DDA}$	—	0.011	1	$\mu A$
ADC asynchronous clock source	High speed (ADLPC = 0)	P	$f_{ADACK}$	2	3.3	5	MHz

Table continues on the next page...

## 6.3.2 Analog comparator (ACMP) electricals

**Table 14. Comparator electrical specifications**

C	Characteristic	Symbol	Min	Typical	Max	Unit
D	Supply voltage	$V_{DDA}$	2.7	—	5.5	V
T	Supply current (Operation mode)	$I_{DDA}$	—	10	20	$\mu A$
D	Analog input voltage	$V_{AIN}$	$V_{SS} - 0.3$	—	$V_{DDA}$	V
P	Analog input offset voltage	$V_{AIO}$	—	—	40	mV
C	Analog comparator hysteresis (HYST=0)	$V_H$	—	15	20	mV
C	Analog comparator hysteresis (HYST=1)	$V_H$	—	20	30	mV
T	Supply current (Off mode)	$I_{DDAOFF}$	—	60	—	nA
C	Propagation Delay	$t_D$	—	0.4	1	$\mu s$

## 6.4 Communication interfaces

### 6.4.1 SPI switching specifications

The serial peripheral interface (SPI) provides a synchronous serial bus with master and slave operations. Many of the transfer attributes are programmable. The following tables provide timing characteristics for classic SPI timing modes. Refer to the SPI chapter of the chip's reference manual for information about the modified transfer formats used for communicating with slower peripheral devices. All timing is shown with respect to 20%  $V_{DD}$  and 70%  $V_{DD}$ , unless noted, and 100 pF load on all SPI pins. All timing assumes high drive strength is enabled for SPI output pins.

**Table 15. SPI master mode timing**

Nu m.	Symbol	Description	Min.	Max.	Unit	Comment
1	$f_{op}$	Frequency of operation	$f_{Bus}/2048$	$f_{Bus}/2$	Hz	$f_{Bus}$ is the bus clock
2	$t_{SPSCK}$	SPSCK period	$2 \times t_{Bus}$	$2048 \times t_{Bus}$	ns	$t_{Bus} = 1/f_{Bus}$
3	$t_{Lead}$	Enable lead time	1/2	—	$t_{SPSCK}$	—
4	$t_{Lag}$	Enable lag time	1/2	—	$t_{SPSCK}$	—
5	$t_{WSPSCK}$	Clock (SPSCK) high or low time	$t_{Bus} - 30$	$1024 \times t_{Bus}$	ns	—
6	$t_{SU}$	Data setup time (inputs)	15	—	ns	—
7	$t_{HI}$	Data hold time (inputs)	0	—	ns	—
8	$t_v$	Data valid (after SPSCK edge)	—	25	ns	—
9	$t_{HO}$	Data hold time (outputs)	0	—	ns	—
10	$t_{RI}$	Rise time input	—	$t_{Bus} - 25$	ns	—

Table continues on the next page...



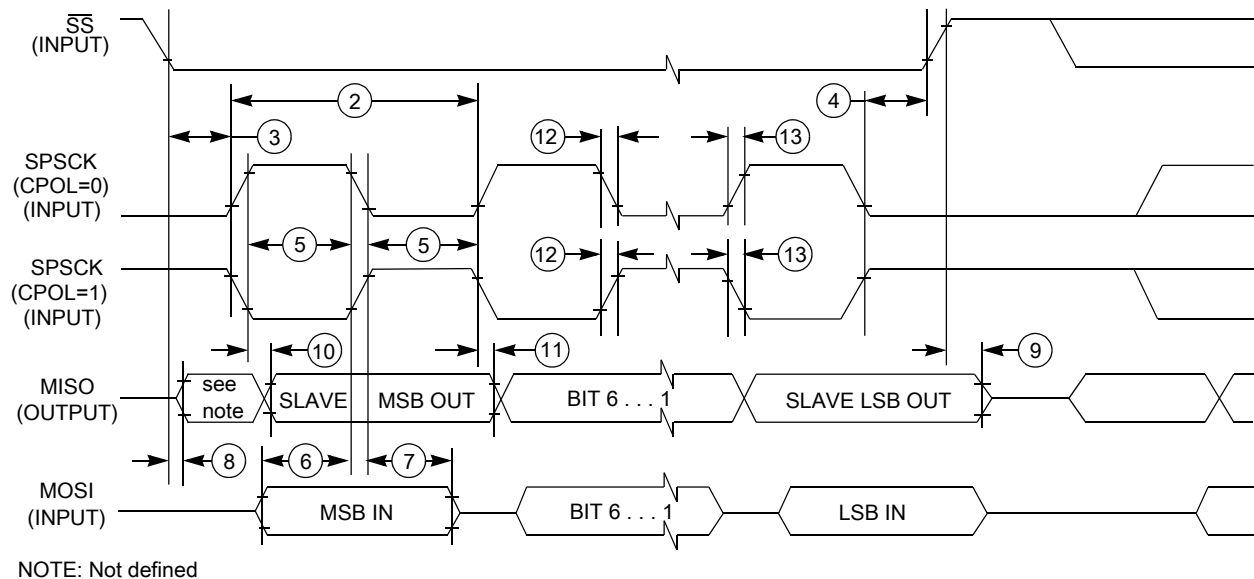


Figure 20. SPI slave mode timing (CPHA=1)

## 7 Dimensions

### 7.1 Obtaining package dimensions

Package dimensions are provided in package drawings.

To find a package drawing, go to [freescale.com](http://freescale.com) and perform a keyword search for the drawing's document number:

If you want the drawing for this package	Then use this document number
16-pin TSSOP	98ASH70247A
20-pin SOIC	98ASB42343B
20-pin TSSOP	98ASH70169A
32-pin LQFP	98ASH70029A
44-pin LQFP	98ASS23225W

**Table 17. Pin availability by package pin-count (continued)**

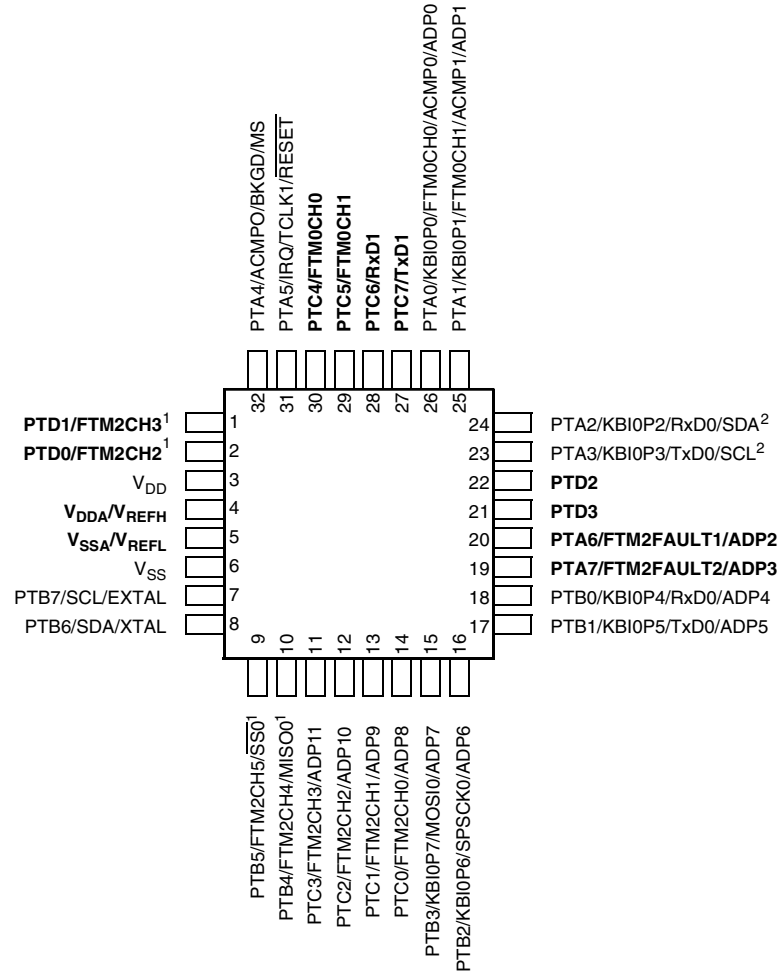
Pin Number				Lowest Priority <-- --> Highest				
44-LQFP	32-LQFP	20-TSSOP	16-TSSOP	Port Pin	Alt 1	Alt 2	Alt 3	Alt 4
29	—	—	—	PTD4	—	—	—	—
30	21	—	—	PTD3	—	—	—	—
31	22	—	—	PTD2	—	—	—	—
32	23	17	13	PTA3 <sup>2</sup>	KBI0P3	TXD0	SCL	—
33	24	18	14	PTA2 <sup>2</sup>	KBI0P2	RXD0	SDA	—
34	25	19	15	PTA1	KBI0P1	FTM0CH1	ACMP1	ADP1
35	26	20	16	PTA0	KBI0P0	FTM0CH0	ACMP0	ADP0
36	27	—	—	PTC7	—	TxD1	—	—
37	28	—	—	PTC6	—	RxD1	—	—
38	—	—	—	PTE2	—	MISO0	—	—
39	—	—	—	PTE1	—	MOSI0	—	—
40	—	—	—	PTE0	—	SPSCK0	—	—
41	29	—	—	PTC5	—	FTM0CH1	—	—
42	30	—	—	PTC4	—	FTM0CH0	—	—
43	31	1	1	PTA5	IRQ	TCLK0	—	RESET
44	32	2	2	PTA4	—	ACMPO	BKGD	MS

1. This is a high current drive pin when operated as output.
2. This is a true open-drain pin when operated as output.

## Note

When an alternative function is first enabled, it is possible to get a spurious edge to the module. User software must clear any associated flags before interrupts are enabled. The table above illustrates the priority if multiple modules are enabled. The highest priority module will have control over the pin. Selecting a higher priority pin function with a lower priority function already enabled can cause spurious edges to the lower priority module. Disable all modules that share a pin before enabling another module.

## 8.2 Device pin assignment

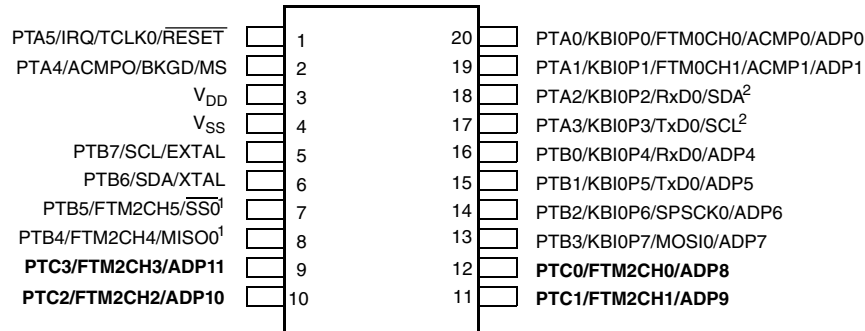


Pins in **bold** are not available on less pin-count packages.

1. High source/sink current pins

2. True open drain pins

**Figure 22. MC9S08PA16 32-pin LQFP package**

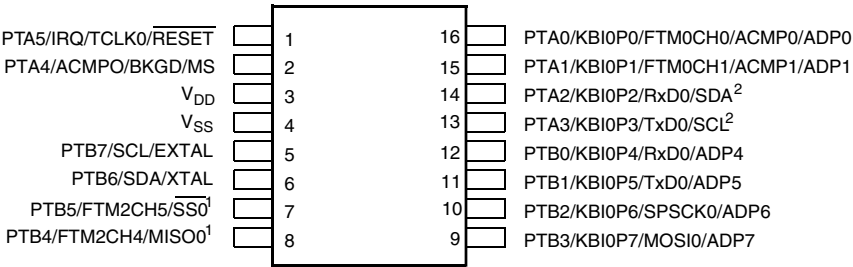


Pins in **bold** are not available on less pin-count packages.

1. High source/sink current pins

2. True open drain pins

**Figure 23. MC9S08PA16 20-pin SOIC and TSSOP package**



Pins in **bold** are not available on less pin-count packages.  
 1. High source/sink current pins  
 2. True open drain pins

Figure 24. MC9S08PA16 16-pin TSSOP package

# 9 Revision history

The following table provides a revision history for this document.

Table 18. Revision history

Rev. No.	Date	Substantial Changes
1	10/2012	Initial public release
2	09/2014	<ul style="list-style-type: none"> <li>Updated <math>V_{OH}</math> and <math>V_{OL}</math> in <a href="#">DC characteristics</a></li> <li>Updated footnote on the <math>S3I_{DD}</math> in <a href="#">Supply current characteristics</a></li> <li>Added <a href="#">EMC radiated emissions operating behaviors</a></li> <li>Updated the typical of <math>f_{int\_t}</math> to 31.25 kHz and updated footnote to <math>t_{Acquire}</math> in <a href="#">External oscillator (XOSC) and ICS characteristics</a></li> <li>Updated the assumption for all the timing values in <a href="#">SPI switching specifications</a></li> <li>Updated the rating descriptions for <math>t_{Rise}</math> and <math>t_{Fall}</math> in <a href="#">Control timing</a></li> <li>Updated the part number format to add new field for new part numbers in <a href="#">Fields</a></li> </ul>
3	06/2015	<ul style="list-style-type: none"> <li>Corrected the Min. of the <math>t_{extrst}</math> in <a href="#">Control timing</a></li> <li>Updated <a href="#">Thermal characteristics</a> to add footnote to the <math>T_A</math> and removed redundant information.Updated the symbol of <math>\theta_{JA}</math> to <math>R_{\theta JA}</math>.</li> </ul>

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